



# Diode Module

## AMDD170N16S



### Key Parameters

$I_{F(AV)M}$	=	170	A
$V_{RRM}$	=	1600	V
$I_{FSM}$	=	6600	A
$V_{TO}$	=	0.75	V
$r_T$	=	1.05	$\text{m}\Omega$

### Properties

- International standard package
- High operation reliability
- Electrically insulated base plate

### MAXIMUM ALLOWABLE RATINGS

Symbols and parameters			Maximum Limits	Unit
$V_{RRM}$	Repetitive peak reverse voltage	$T_{vj} = -40^\circ\text{C} \dots T_{vj \text{ max}}$	1600	V
$V_{RSM}$	Non-repetitive peak reverse voltage	$T_{vj} = +25^\circ\text{C} \dots T_{vj \text{ max}}$	1700	V
$I_{FAVM}$	Average on-state current	$T_C = 100^\circ\text{C}$	165	A
$I_{FRMSM}$	Maximum RMS on-state current		260	A
$I_{FSM}$	Surge current	$T_{vj} = 25^\circ\text{C}, t_p = 10 \text{ ms}$ $T_{vj} = T_{vj \text{ max}}, t_p = 10 \text{ ms}$	6600 5500	A A
$I^2t$	Safety factor	$T_{vj} = 25^\circ\text{C}, t_p = 10 \text{ ms}$ $T_{vj} = T_{vj \text{ max}}, t_p = 10 \text{ ms}$	217800 151250	$\text{A}^2\text{s}$ $\text{A}^2\text{s}$

## CHARACTERISTICS

Symbols and parameters		Value			Unit
		min	typ	max	
<b>V<sub>F</sub></b>	On-state voltage	T <sub>vj</sub> = 25°C, I <sub>F</sub> = 500 A		1.4	V
<b>V<sub>(TO)</sub></b>	Threshold voltage	T <sub>vj</sub> = T <sub>vj max</sub>		0.75	V
<b>r<sub>T</sub></b>	Slope resistance	T <sub>vj</sub> = T <sub>vj max</sub>		1.05	mΩ
<b>I<sub>R</sub></b>	Reverse current	T <sub>vj</sub> = T <sub>vj max</sub> , V <sub>R</sub> = V <sub>RRM</sub>		9	mA
<b>V<sub>ISOL</sub></b>	Insulation test voltage	RMS, f = 50Hz, t = 1 sec RMS, f = 50Hz, t = 1 min		3.6 3.0	kV

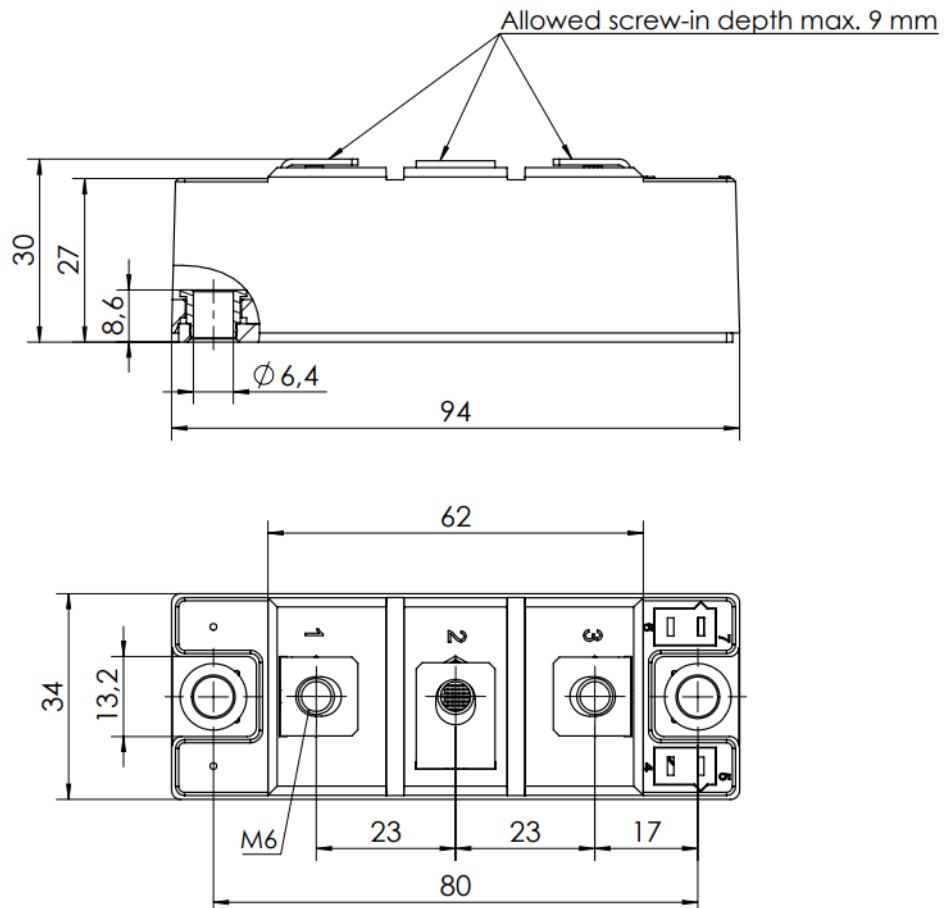
## THERMAL PARAMETERS

Symbols and parameters			Value	Unit
<b>R<sub>th(j-c)</sub></b>	Thermal resistance, junction to case	per Module, θ = 180° sin per arm, θ = 180° sin per Module, DC per arm, DC	0.09 0.18 0.09 0.18	K/W
<b>R<sub>th(c-h)</sub></b>	Thermal resistance, case to heatsink	per Module per arm	0.05 0.10	K/W
<b>T<sub>vj max</sub></b>	Maximum junction temperature		+135	°C
<b>T<sub>C op</sub></b>	Operating temperature range		-40...+125	°C
<b>T<sub>stg</sub></b>	Storage temperature range		-40...+125	°C

## MECHANICAL PARAMETERS

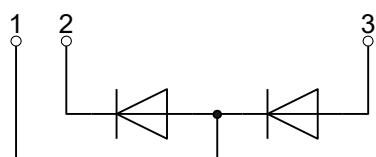
Symbols and parameters			Value	Unit
<b>M1</b>	Mounting torque	Tolerance ± 15%	5	Nm
<b>M2</b>	Terminal connection torque	Tolerance ± 15%	5	Nm
<b>W</b>	Weight		165	g
<b>a</b>	Vibration resistance	f = 50 Hz	50	m/s <sup>2</sup>

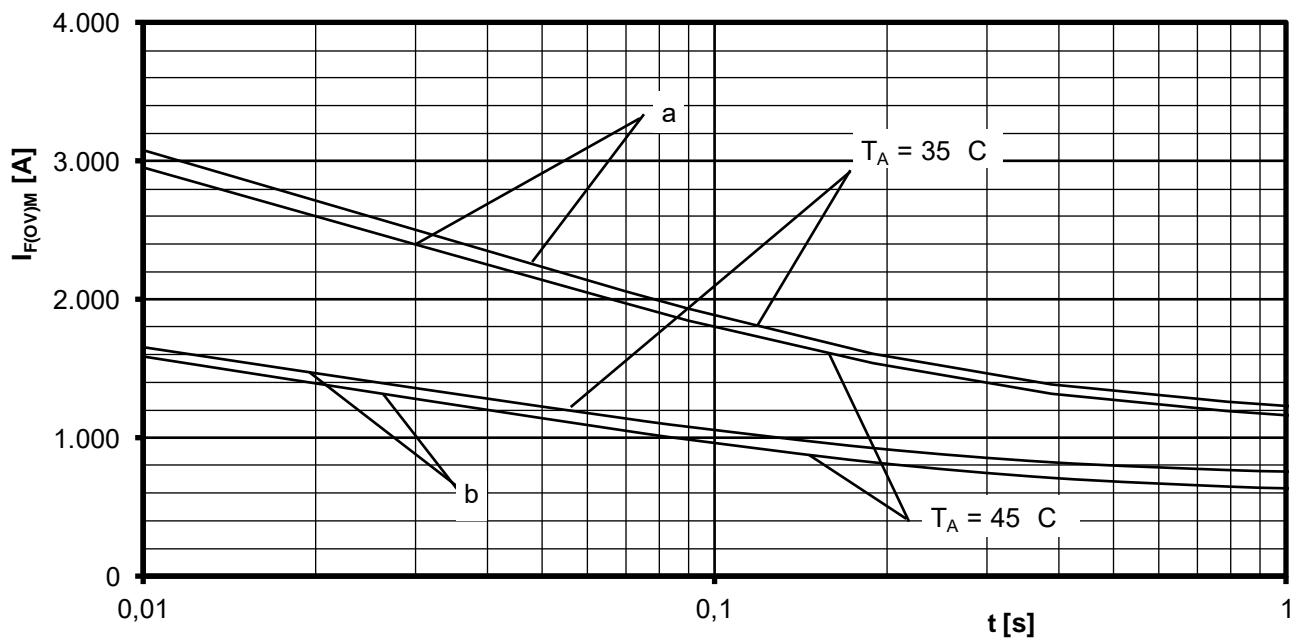
## DIMENSIONS



General tolerance  $\pm 0,5$  mm

## TOPOLOGY OF INTERNAL CONNECTION





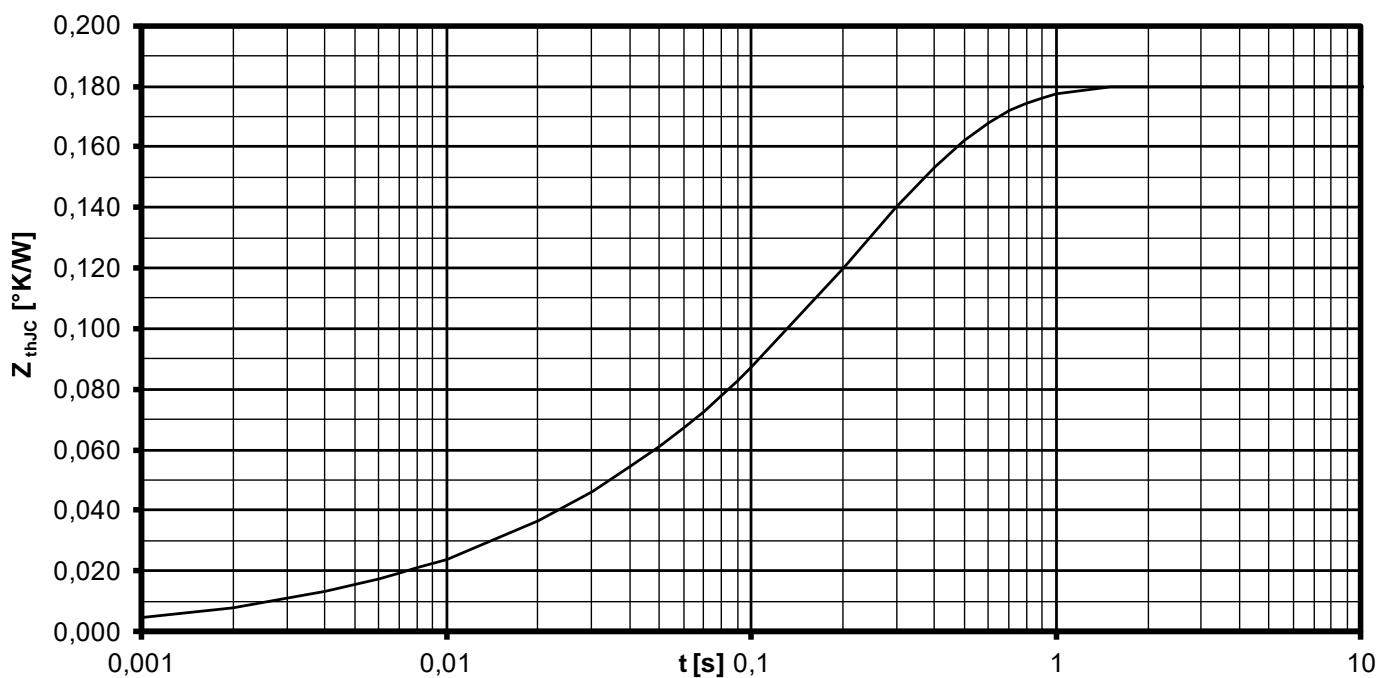
**Maximum overload on-state current per arm  $I_{F(OV)M} = f(t)$ ,  $V_{RM} = 0,8 V_{RRM}$**

a: No-load conditions

b: Pre-load current per arm  $I_{FAV(vor)} = I_{FAVM}$

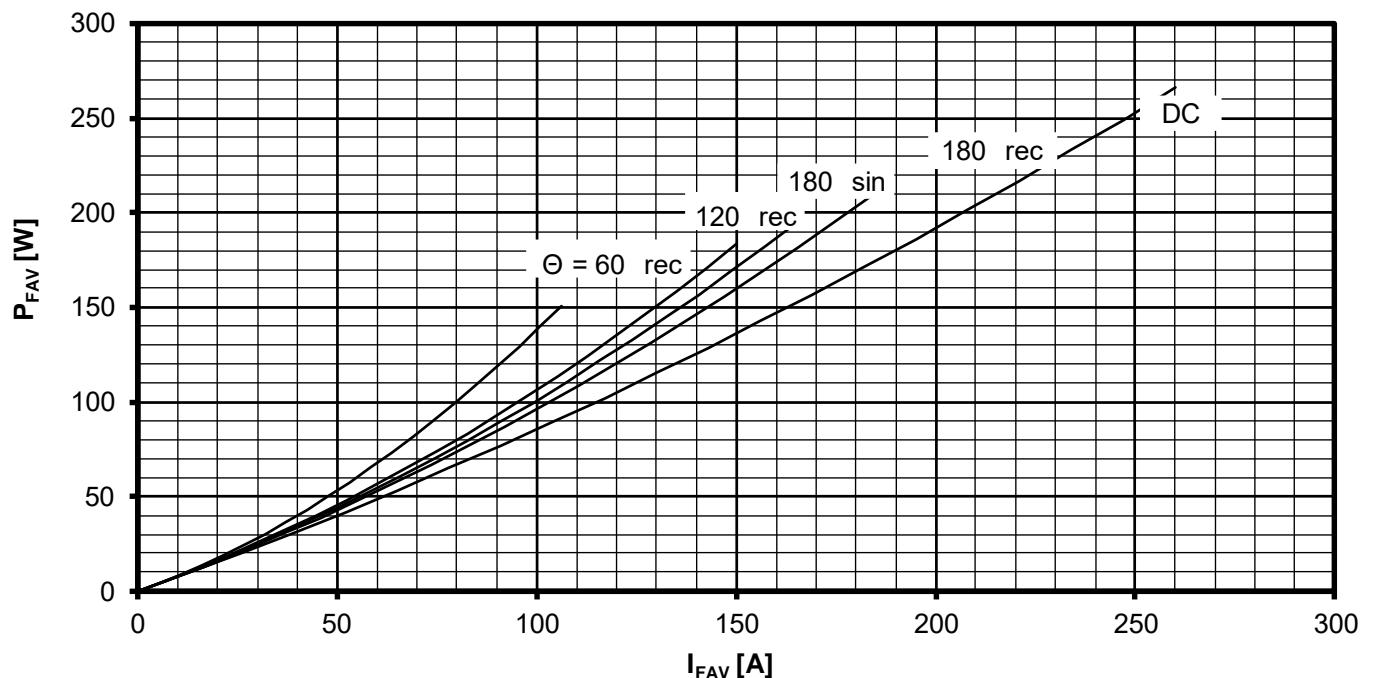
$T_a = 35^\circ\text{C}$ , Forced air cooling Heatsink type: KM17 (Papst 4650)

$T_a = 45^\circ\text{C}$ , Natural air cooling Heatsink type: KM17 (160W)



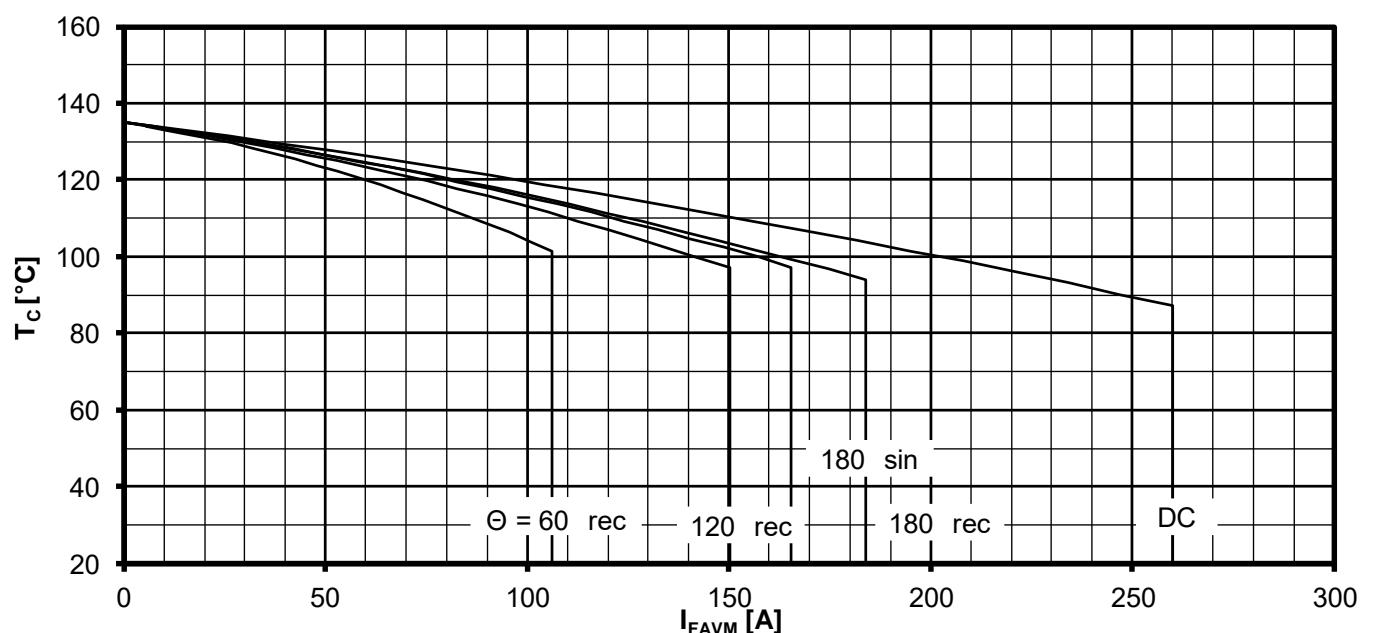
**Transient thermal impedance per arm  $Z_{thJC} = f(t)$**

Parameter: Current conduction angle  $\Theta$



On-state power loss per arm  $P_{FAV} = f(I_{FAV})$

Parameter: Current conduction angle  $\Theta$

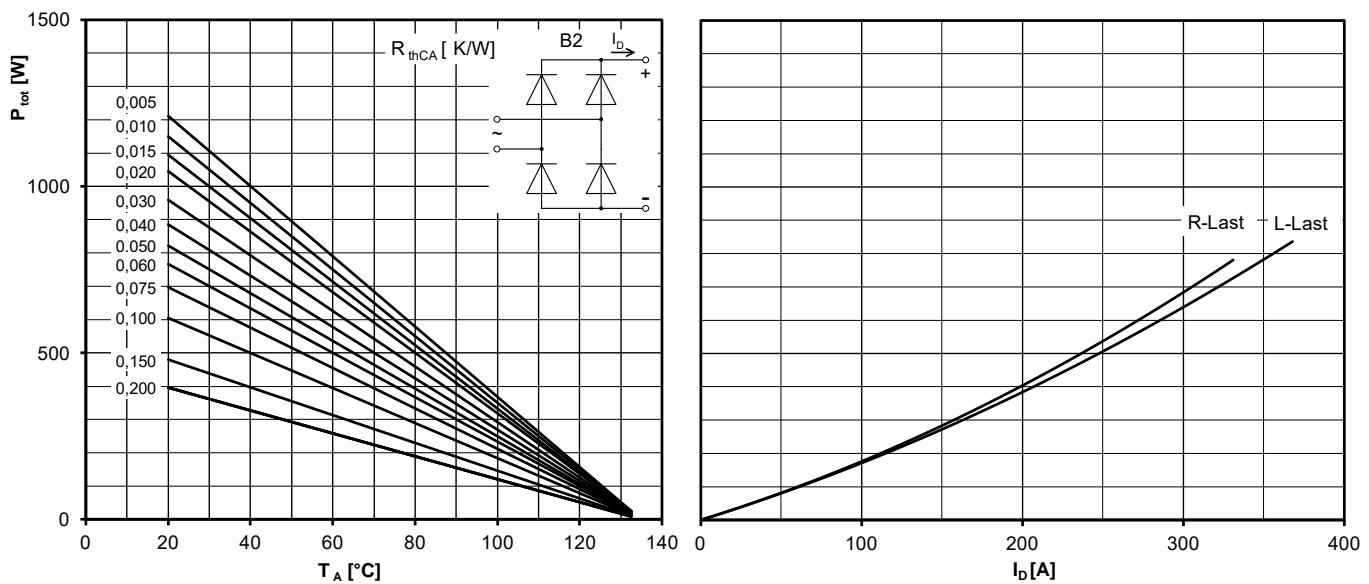


Maximum allowable case temperature  $T_c = f(I_{FAQM})$

Current load per arm

Calculation base  $P_{TAV}$

Parameter: Current conduction angle  $\Theta$



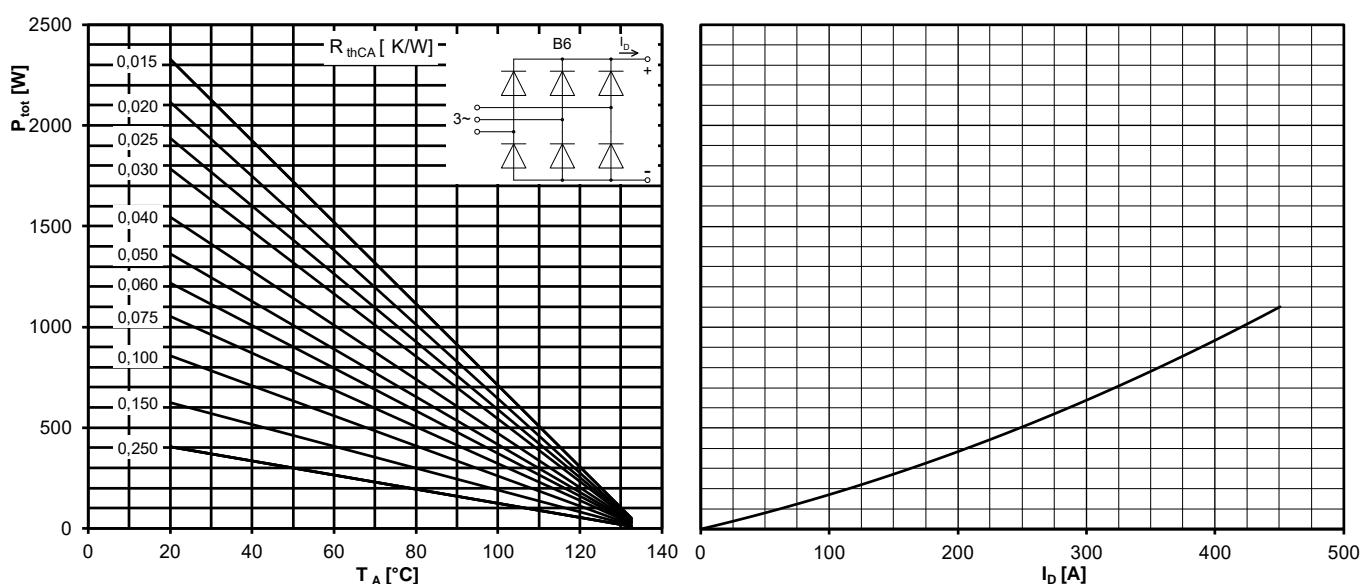
**Maximum rated output current  $I_D$**

B2- Two-pulse bridge circuit

Total power dissipation at circuit  $P_{\text{tot}}$

Parameter:

Thermal resistance cases to ambient  $R_{\text{thCA}}$



**Maximum rated output current  $I_D$**

B6- Six-pulse bridge circuit

Total power dissipation at circuit  $P_{\text{tot}}$

Parameter:

Thermal resistance cases to ambient  $R_{\text{thCA}}$